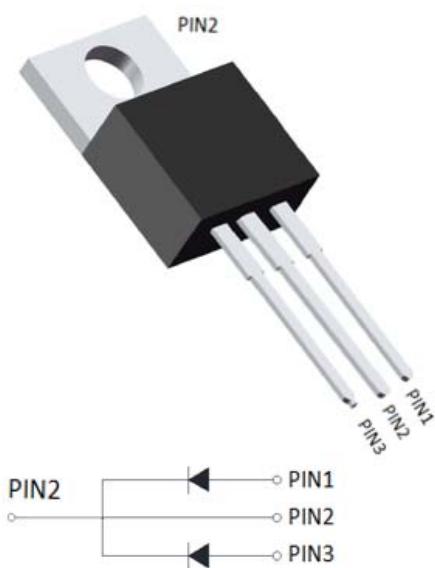


Schottky Diodes



Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-220AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR3060CTTS
Device marking code			MBR3060CTTS
Repetitive Peak Reverse Voltage	V _{RRM}	V	60
Average Rectified Output Current @60Hz sine wave, R-load, T _c (FIG.1)	I _O	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave,1 cycle, Ta=25°C	I _{FSM}	A	260
Current Squared Time @1ms≤t≤8.3ms T _j =25°C,	I ² t	A ² s	280
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR3060CTTS
Maximum instantaneous forward voltage drop per diode	V _{FM}	V	I _{FM} =15.0A	0.80
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	V _{RM} =V _{RRM} T _a =25°C	0.1
	I _{RRM2}		V _{RM} =V _{RRM} T _a =125°C	20

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS



MBR3060CTTS

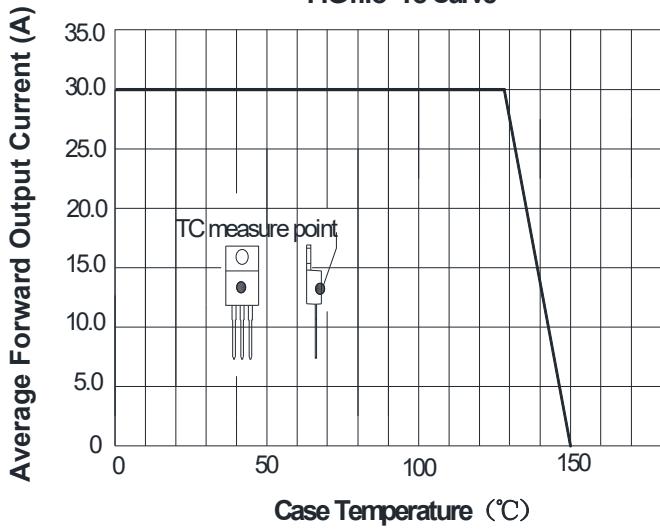
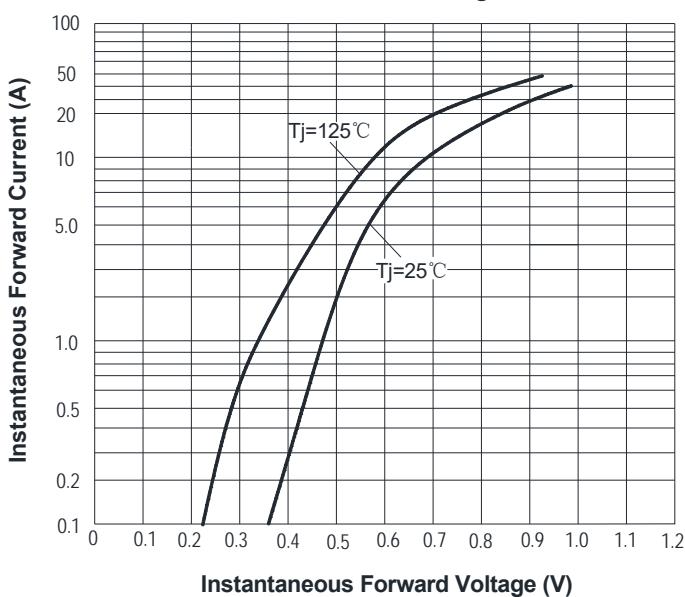
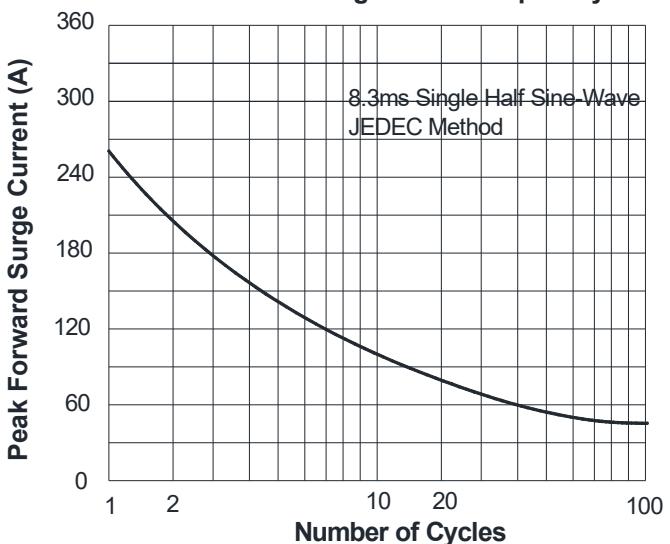
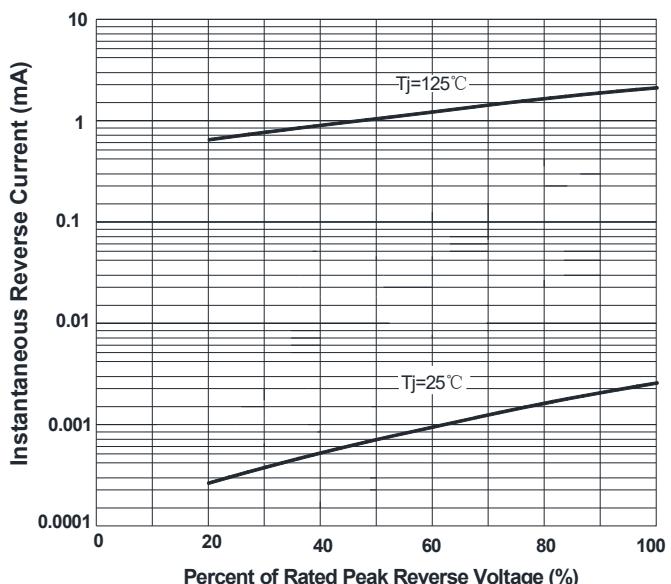
■ Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR3060CTTS
Thermal Resistance	Between junction and case	R _{θJ-C}	°C/W	2.0

■ Ordering Information (Example)

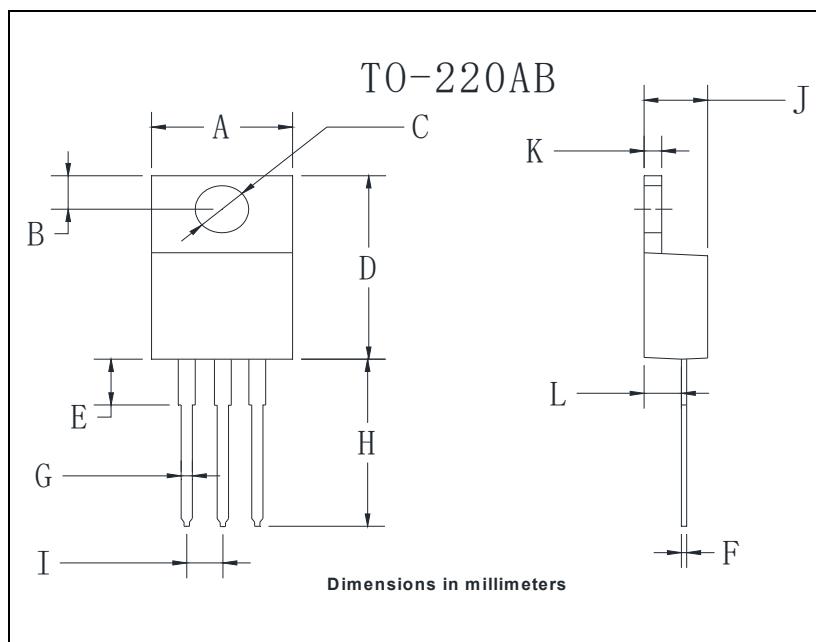
PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR3060CTTS	Approximate 1.9	50	1000	5000	Tube

■ Characteristics (Typical)

FIG1:Io -Tc Curve**FIG3: Forward Voltage****FIG2: Forward Surge Current Capability****FIG4: Typical Reverse Characteristics**



■Outline Dimensions



TO-220AB		
Dim	Min	Max
A	9.95	10.35
B	2.55	2.95
C	3.8	4.0
D	14.95	15.25
E	3.75	4.25
F	0.26	0.5
G	0.68	0.94
H	13.4	13.9
I	2.35	2.65
J	4.38	4.78
K	1.14	1.4
L	2.37	2.79



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